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VBT30L60C-E3, VBT30L60C-M3, VBT30L60CHM3

Vishay General Semiconductor

# **Dual Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.32$  V at  $I_F = 5.0$  A



#### VBT30L60C

PIN 2 O

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 15 A			
V <sub>RRM</sub>	60 V			
I <sub>FSM</sub>	200 A			
$V_F$ at $I_F = 15$ A	0.45 V			
T <sub>J</sub> max.	150 °C			
Package	TO-263AB			
Diode variation	Dual common cathode			

## FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- AEC-Q101 qualified available - Automotive ordering code: base P/NHM3
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Not recommended for PCB bottom side wave mounting
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## **TYPICAL APPLICATIONS**

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

### **MECHANICAL DATA**

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3, M3, and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VBT30L60C	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	60	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	30	٨	
	per diode		15	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	200	А	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +150	°C	

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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25$ °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MIN.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 5.0 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> (1)	0.43	-	V
	I <sub>F</sub> = 7.5 A			0.46	-	
	I <sub>F</sub> = 15 A			0.51	0.60	
	$I_{F} = 5.0 \text{ A}$	T <sub>A</sub> = 125 °C		0.32	-	
	I <sub>F</sub> = 7.5 A			0.36	-	
	I <sub>F</sub> = 15 A			0.45	0.57	
Reverse current per diode	V - 60 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	_	4.0	mA
	$V_R = 60 V$ $T_A =$	T <sub>A</sub> = 125 °C		27	110	

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  40 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	VBT30L60C	UNIT	
Typical thermal resistance	per diode	$R_{ ext{ heta}JC}$	1.8	°C/W	
	per device		0.8	0/22	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VBT30L60C-E3/4W	1.39	4W	50/tube	Tube	
TO-263AB	VBT30L60C-E3/8W	1.39	8W	800/reel	Tape and reel	
TO-263AB	VBT30L60C-M3/I	1.39	I	800/reel	Tape and reel	
TO-263AB	VBT30L60CHM3/I <sup>(1)</sup>	1.39	I	800/reel	Tape and reel	

Note

<sup>(1)</sup> AEC-Q101 qualified

## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

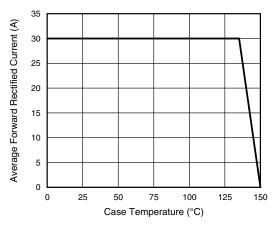


Fig. 1 - Maximum Forward Current Derating Curve

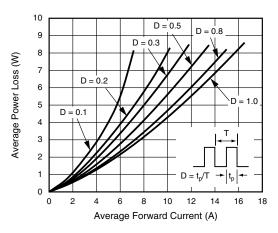


Fig. 2 - Forward Power Dissipation Characteristics Per Diode

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## VBT30L60C-E3, VBT30L60C-M3, VBT30L60CHM3

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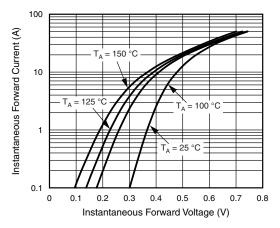


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

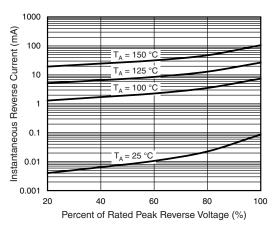


Fig. 4 - Typical Reverse Characteristics Per Diode

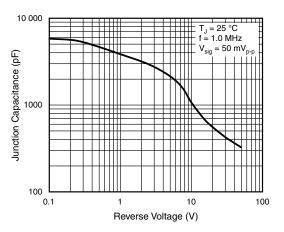


Fig. 5 - Typical Junction Capacitance Per Diode

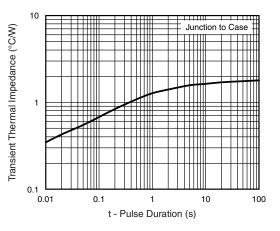
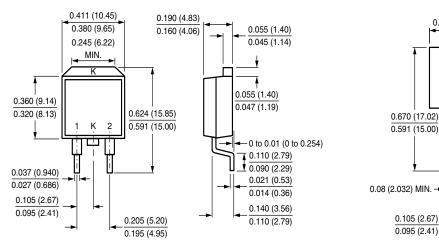


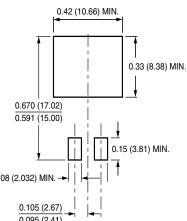
Fig. 6 - Typical Transient Thermal Impedance Per Diode

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



#### TO-263AB

**Mounting Pad Layout** 



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